Amplifier Transistors

Voltage and Current are Negative for PNP Transistors

Features

• Pb–Free Packages are Available*



ON Semiconductor®

http://onsemi.com



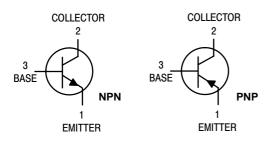
MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V _{CEO}	20	Vdc
Collector – Emitter Voltage	V _{CES}	25	Vdc
Emitter – Base Voltage	V _{EBO}	5.0	Vdc
Collector Current – Continuous	Ι _C	1.0	Adc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D 1.5 12		W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

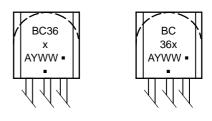
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction–to–Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction–to–Case	$R_{\theta JC}$	83.3	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MARKING DIAGRAMS



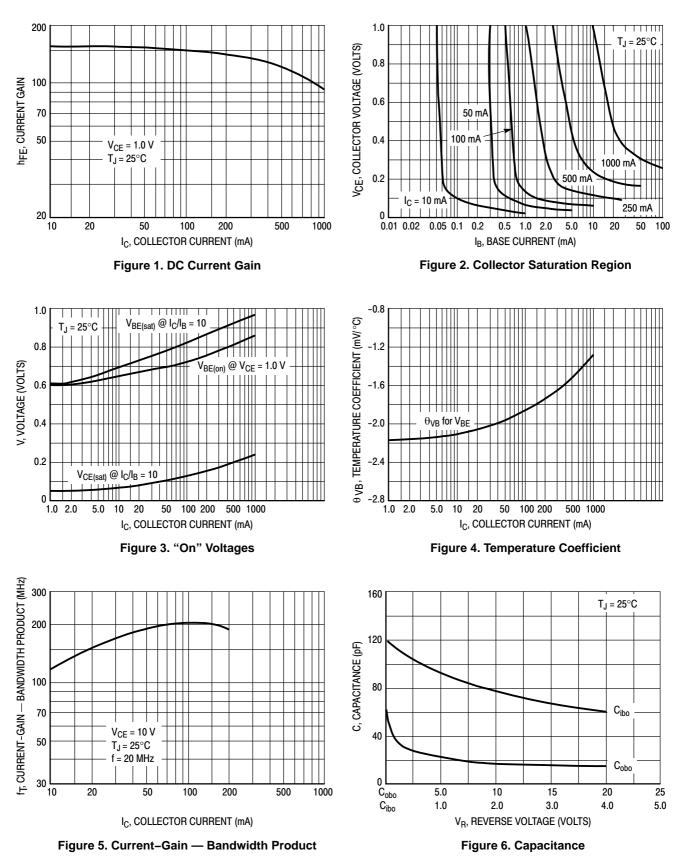
BC36x	=	Device Code
		x = 8 or 9
A	=	Assembly Location
Y	=	Year
WW	=	Work Week
•	=	Pb–Free Package
(Note: Microe	dot	may be in either location)

ORDERING INFORMATION

Device	Package	Shipping		
BC368	TO-92	5000 Units/Box		
BC368G	TO-92 (Pb-Free)	5000 Units/Box		
BC368ZL1	TO-92	2000/Ammo Box		
BC368ZL1G	TO-92 (Pb-Free)	2000/Ammo Box		
BC369	TO-92	5000 Units/Box		
BC369G	TO-92 (Pb-Free)	5000 Units/Box		
BC369ZL1	TO-92	2000/Ammo Box		
BC369ZL1G	TO–92 (Pb–Free)	2000/Ammo Box		

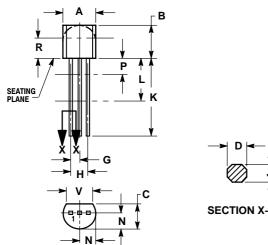
ELECTRICAL CHARACTERISTICS (T_A = 25° C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage $(I_C = 10 \text{ mA}, I_B = 0)$	V _{(BR)CEO}	20	-	-	Vdc
Collector – Base Breakdown Voltage $(I_C = 100 \ \mu\text{A}, I_E = 0)$	V _{(BR)CBO}	25	-	-	Vdc
Emitter – Base Breakdown Voltage $(I_E = 100 \ \mu A, I_C = 0)$	V _{(BR)EBO}	5.0	-	-	Vdc
Collector Cutoff Current $(V_{CB} = 25 \text{ V}, I_E = 0)$ $(V_{CB} = 25 \text{ V}, I_E = 0, T_J = 150^{\circ}\text{C})$	I _{CBO}			10 1.0	μAdc mAdc
Emitter Cutoff Current ($V_{EB} = 5.0 \text{ V}, I_C = 0$)	I _{EBO}	-	_	10	μAdc
ON CHARACTERISTICS					
$ \begin{array}{l} \mbox{DC Current Gain} \\ (V_{CE} = 10 \ \mbox{V}, \ \mbox{I}_{C} = 5.0 \ \mbox{mA}) \\ (V_{CE} = 1.0 \ \mbox{V}, \ \mbox{I}_{C} = 0.5 \ \mbox{A}) \\ & \ \mbox{BC368, 369} \\ & \ \mbox{BC368-25} \\ (V_{CE} = 1.0 \ \mbox{V}, \ \mbox{I}_{C} = 1.0 \ \mbox{A}) \\ \end{array} $	h _{FE}	50 85 170 60	- - - -	- 375 375 -	-
Bandwidth Product ($I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 20 \text{ MHz}$)	fT	65	-	-	MHz
Collector–Emitter Saturation Voltage $(I_C = 1.0 \text{ A}, I_B = 100 \text{ mA})$	V _{CE(sat)}	-	_	0.5	V
Base–Emitter On Voltage $(I_C = 1.0 \text{ A}, V_{CE} = 1.0 \text{ V})$	V _{BE(on)}	-	_	1.0	V



PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AL**





NOTES

- DIMENSIONING AND TOLERANCING PER ANSI 1. Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- 2. CONTOUR OF PACKAGE BEYOND DIMENSION R
- 3. IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM. 4.

	INCHES		MILLIM	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
Κ	0.500		12.70	
L	0.250		6.35	
Ν	0.080	0.105	2.04	2.66
Ρ		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	

STYLE 14: PIN 1. EMITTER 2. COLLECTOR

3. BASE

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